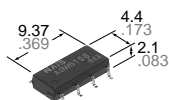




GU (General Use) Type SOP Series [2-Channel (Form A/Form B) Type]

PhotoMOS RELAYS

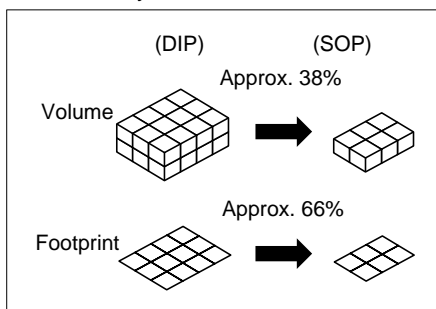


mm inch

FEATURES

1. 2 channels in super miniature design

The device comes in a super-miniature SO package measuring (W) 4.4 × (L) 9.37 × (H) 2.1 mm (W) .173 × (L) .369 × (H) .083 inch —approx. 38% of the volume and 66% of the footprint size of DIP type PhotoMOS Relays.



2. Tape and reel

The device comes standard in a tape and reel (1,000 pcs./reel) to facilitate automatic insertion machines.

Applicable for 1 Form A 1 Form B use as well as two independent 1 Form A and 1 Form B use

Controls low-level analog signals
PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion

5. Low-level off state leakage current

TYPICAL APPLICATIONS

- Telephones
- Measuring instruments
- Computer
- Industrial robots
- High-speed inspection machines.

TYPES

1. AC/DC type

Output rating*		Part No.		Packing quantity in tape and reel
Load voltage	Load current	Picked from the 1/2/3/4-pin side	Picked from the 5/6/7/8-pin side	
350 V	100 mA	AQW610SX	AQW610SZ	1,000 pcs.

*Indicate the peak AC and DC values.

Notes: (1) Tape package is the standard packing style. Also available in tube. (Part No. suffix "X" or "Z" is not needed when ordering; Tube: 50 pcs.; Case: 1,000 pcs.)

(2) For space reasons, the package type indicator "X" and "Z" are omitted from the seal.

RATING

1. AC/DC type

1. Absolute maximum ratings (Ambient temperature : 25°C 77°F)

Item	Symbol	AQW610S	Remarks	
Input	LED forward current	I _F	50 mA	
	LED reverse voltage	V _R	3 V	
	Peak forward current	I _{FP}	1 A	f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P _{in}	75 mW	
Output	Load voltage (peak AC)	V _L	350 V	
	Continuous load current	I _L	0.1 A (0.13 A)	(): in case of using only 1 channel
	Peak load current	I _{peak}	0.3 A	100 ms (1 shot), V _L = DC
	Power dissipation	P _{out}	600 mW	
Total power dissipation	P _T	650 mW		
I/O isolation voltage	V _{iso}	1,500 V AC		
Temperature limits	Operating	T _{opr}	-40°C to +85°C -40°F to +185°F	Non-condensing at low temperatures
	Storage	T _{stg}	-40°C to +100°C -40°F to +212°F	

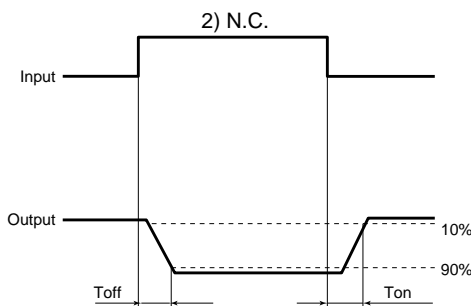
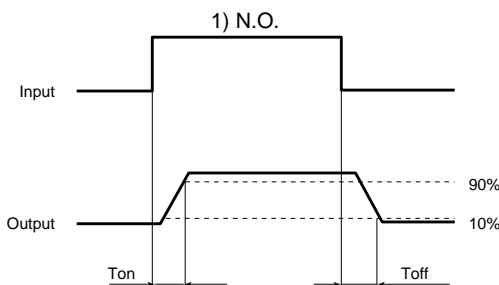
AQW610S

2. Electrical characteristics (Ambient temperature : 25°C 77°F)

Item			Symbol	AQW610S	Condition
Input	LED operate current	Typical	I_{Fon}	0.9 mA	$I_L = \text{Max.}$
		Maximum		3 mA	
	LED reverse current	Minimum	I_{Foff}	0.4 mA	$I_L = \text{Max.}$
		Typical		0.8 mA	
LED dropout voltage	Typical	V_F	1.14 V (1.25 V at $I_F = 50 \text{ mA}$)	$I_F = 5 \text{ mA}$	
	Maximum		1.5 V		
Output	On resistance	Typical	R_{on}	18 Ω	$I_F = 5 \text{ mA (N.O.)}$ $I_F = 0 \text{ mA (N.C.)}$ $I_L = \text{Max.}$ Within 1 s on time
		Maximum		25 Ω	
	Off state leakage current	Maximum	I_{leak}	1 μA	$I_F = 0 \text{ mA (N.O.)}$ $I_F = 5 \text{ mA (N.C.)}$ $V_L = \text{Max.}$
Transfer characteristics	Operate time*	Typical	T_{on}	0.28 ms (N.O.), 0.52 ms (N.C.)	$I_F = 0 \text{ mA} \rightarrow 5 \text{ mA}$ $I_L = \text{Max.}$
		Maximum		1.0 ms	
	Reverse time*	Typical	T_{off}	0.04 ms (N.O.), 0.23 ms (N.C.)	$I_F = 5 \text{ mA} \rightarrow 0 \text{ mA}$ $I_L = \text{Max.}$
		Maximum		1.0 ms	
	I/O capacitance	Typical	C_{iso}	0.8 pF	$f = 1 \text{ MHz}$ $V_B = 0$
Maximum		1.5 pF			
Initial I/O isolation resistance	Minimum	R_{iso}	1,000 M Ω	500 V DC	

Note: Recommendable LED forward current $I_F = 5 \text{ mA}$

*Operate/Reverse time

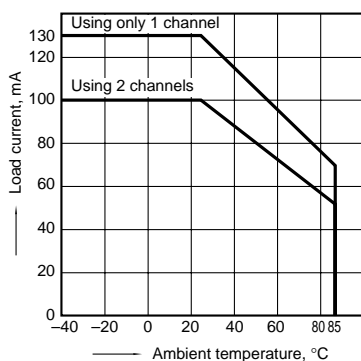


- For Dimensions, see Page 441.
- For Schematic and Wiring Diagrams, see Page 445.
- For Cautions for Use, see Page 449.

REFERENCE DATA

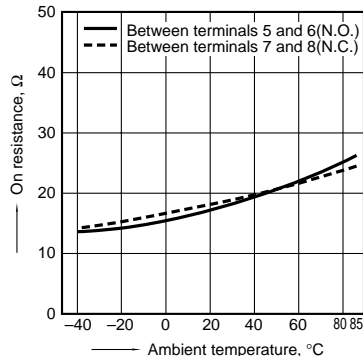
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



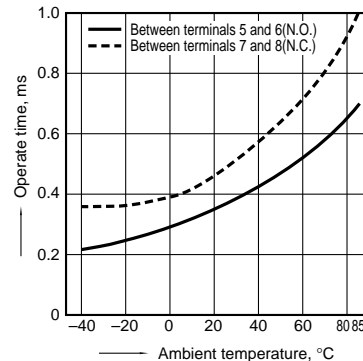
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



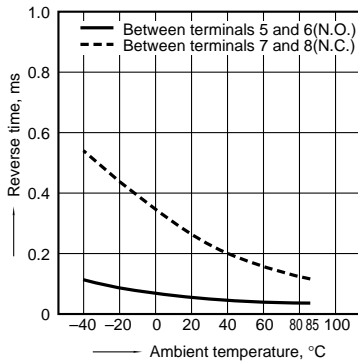
3. Operate time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



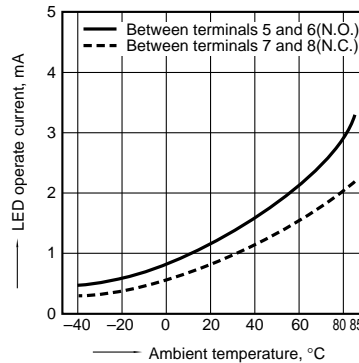
4. Reverse time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



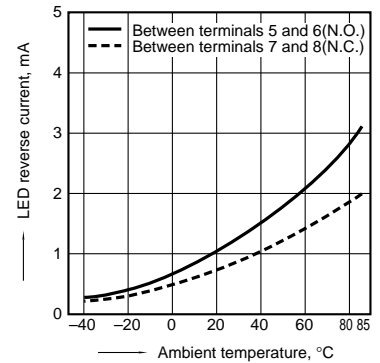
5. LED operate current vs. ambient temperature characteristics

Load voltage: Max. (DC); Continuous load current: Max. (DC)



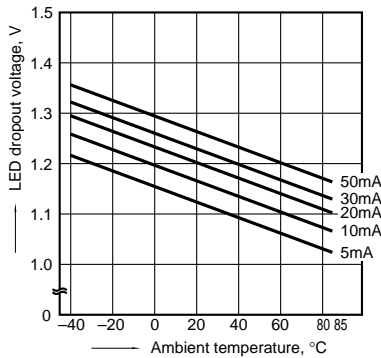
6. LED Reverse current vs. ambient temperature characteristics

Load voltage: Max. (DC); Continuous load current: Max. (DC)



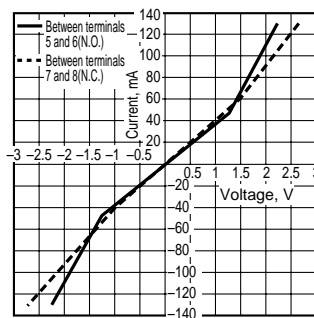
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



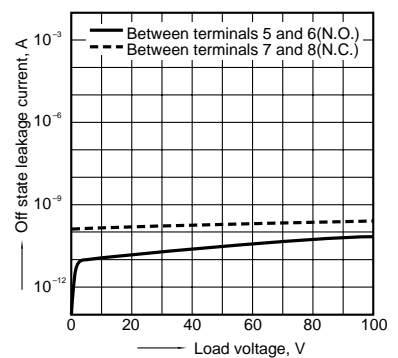
8. Voltage vs. current characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



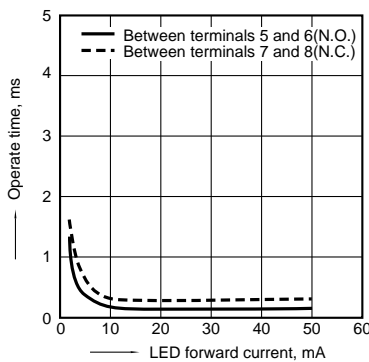
9. Off state leakage current

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



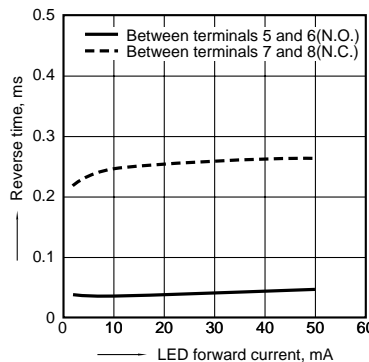
10. LED forward current vs. operate time characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



11. LED forward current vs. reverse time characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



12. Applied voltage vs. output capacitance characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Frequency: 1 MHz; Ambient temperature: 25°C 77°F

